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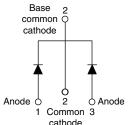


www.vishay.com

## Vishay Semiconductors

## Schottky Rectifier, 2 x 20 A





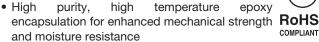
**TO-220AB** 

Base 2 common C cathode	2
<b>A</b>	<b>A</b>
	Anode on the state of the state

PRODUCT SUMMARY						
Package	TO-220AB					
I <sub>F(AV)</sub>	2 x 20 A					
$V_R$	150 V					
V <sub>F</sub> at I <sub>F</sub>	0.71 V					
I <sub>RM</sub> max.	15 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
Diode variation	Common cathode					
E <sub>AS</sub>	1.0 mJ					

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long FREE term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### **DESCRIPTION**

The VS-40CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I <sub>F(AV)</sub>	Rectangular waveform	40	Α				
V <sub>RRM</sub>		150	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1500	Α				
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.71	V				
T <sub>J</sub>		- 55 to 175	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-40CTQ150PbF	VS-40CTQ150-N3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	150	150	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	130	130	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current	per leg		50 % duty cycle at T <sub>C</sub> = 140 °C, rectangular waveform		EO 0/ duty avalo at T 140 °C rectangular variatores		20	
See fig. 5	per device	I <sub>F(AV)</sub>			40	Α		
' '	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500	A		
surge current per leg See fig. 7		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	250			
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.5 A, L = 0.9 mH		1.0	mJ		
Repetitive avalanche current per leg I <sub>AR</sub>		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.5	А		



# VS-40CTQ150PbF, VS-40CTQ150-N3

## Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
Maximum forward voltage drop per leg See fig. 1		20 A	- T <sub>J</sub> = 25 °C -	0.93	V		
	V <sub>FM</sub> <sup>(1)</sup>	40 A		1.16			
		20 A		0.71			
		40 A	T <sub>J</sub> = 125 °C	0.85			
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>B</sub>	50	μΑ		
See fig. 2	IRM (")	T <sub>J</sub> = 125 °C	v <sub>R</sub> = nateu v <sub>R</sub>	15	mA		
Maximum junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		450	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg		В	DC operation See fig. 4	1.5		
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	0.75	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased			
Approvimate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum		New July is estead three add	6 (5)	kgf · cm	
Mounting torque —	maximum		Non-lubricated threads		(lbf $\cdot$ in)	
Marking device			Case style TO-220AB	40CTQ150		

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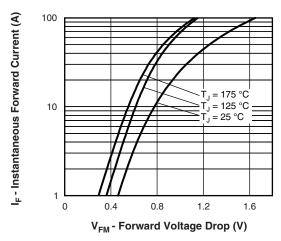


Fig. 1 - Maximum Forward Voltage Drop Characteristics

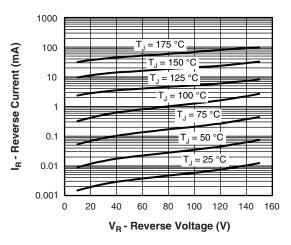


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

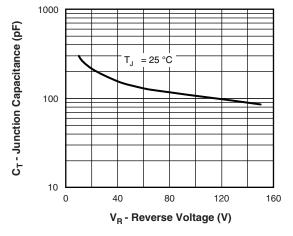


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

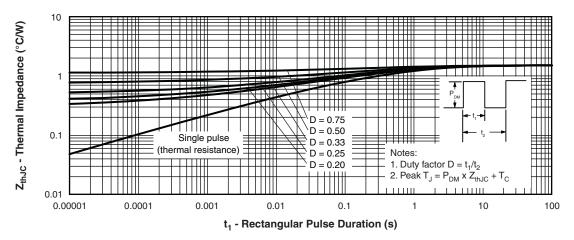


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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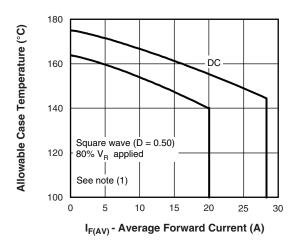


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

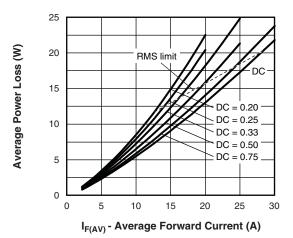


Fig. 6 - Forward Power Loss Characteristics

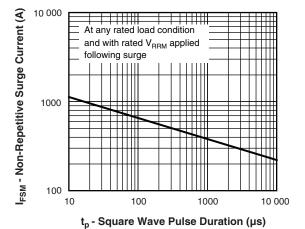


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

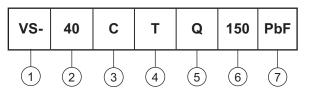
 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % V<sub>R</sub> applied

## VS-40CTQ150PbF, VS-40CTQ150-N3

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### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings (150 = 150 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-40CTQ150PbF	50	1000	Antistatic plastic tube				
VS-40CTQ150-N3	50	1000	Antistatic plastic tube				

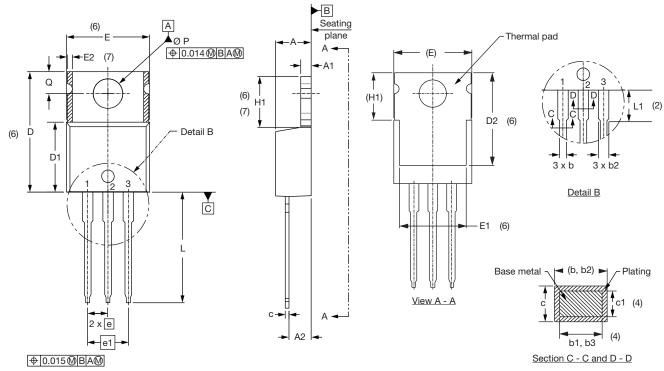
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95222</u>						
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225				
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028				



### Vishay Semiconductors

### **TO-220AB**

### **DIMENSIONS** in millimeters and inches



### Lead assignments



- <u>Diodes</u>
- Anode/open
   Cathode
- 3. Anode

### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

evi	MBOL	MILLIN	IETERS	INC	HES	NOTES
311	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
	Е	10.11	10.51	0.398	0.414	3, 6
	E1	6.86	8.89	0.270	0.350	6
	E2	-	0.76	-	0.030	7
	е	2.41	2.67	0.095	0.105	
	e1	4.88	5.28	0.192	0.208	
	H1	6.09	6.48	0.240	0.255	6, 7
	L	13.52	14.02	0.532	0.552	
	L1	3.32	3.82	0.131	0.150	2
(	ØΡ	3.54	3.73	0.139	0.147	
	Q	2.60	3.00	0.102	0.118	
	θ	90° t	o 93°	90° t	o 93°	

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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